NSN 5961-01-418-1720

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-418-1720 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.360 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage **Current Rating Per Characteristic:** 5.40 amperes source current and 22.00 amperes off-state current, peak **Power Rating Per Characteristic:** 150.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 66948-2001410 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: